TOSHIBA

TOSHIBA Photocoupler IRED & Photo-Transistor

TLP626, TLP626-2, TLP626-4

Programmable Controllers AC / DC-Input Module Telecommunication

The TOSHIBA TLP626, -2 and -4 consist of two infrared emitting diodes connected in inverse parallel, optically coupled to a photo-transistor. The TLP626-2 offers two isolated channels in an eight lead plastic DIP, while the TLP626-4 provides four isolated channels in a sixteen plastic DIP.

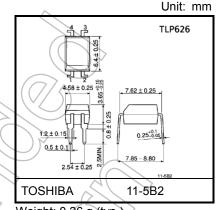
- Collector-emitter voltage: 55 V (min)
- Isolation voltage: 5000 Vrms (min)
- UL-recognized: UL 1577, File No.E67349
- cUL-recognized: CSA Component Acceptance Service No.5A
 - File No.E67349
- VDE-approved: EN 60747-5-5 (Note 1)

Note 1: When a VDE approved type is needed please designate the **Option(D4)**.

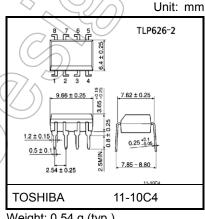
	Curre	ent Transfer Ra	tio (min)	
Classification (Note 1)	Ta =	25°C	Ta = -25 to 75°C	Marking of Classification
	I _F = ±1mA V _{CE} = 0.5V	IF = ±0.5mA V _{CE} = 1.5V	I _F = ±1mA V _{CE} = 0.5V	
Rank BV	200%	100%	100%	BV
Standard	100%	50%	50%	BV, blank
	(Note 1) Rank BV	Classification (Note 1) $I_{F} = \pm 1mA$ $V_{CE} = 0.5V$ Rank BV 200%	Classification (Note 1) $I_{F} = \pm 1 \text{mA}$ $V_{CE} = 0.5 \text{V}$ $I_{F} = \pm 1.5 \text{V}$ Rank BV 200% $100%$	Classification (Note 1) Ta = 25°C Ta = -25 to 75°C IF = ±1mA IF = ±0.5mA IF = ±1mA VCE = 0.5V VCE = 1.5V VCE = 0.5V Rank BV 200% 100% 100%

Note 1: Only TLP626 is applied to BV rank items. Note: Application type name for certification test, please use standard product type name, i.e.

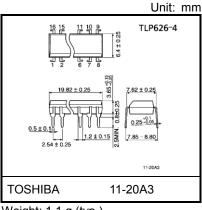
(TLP626(BV): TLP626



Weight: 0.26 g (typ.)

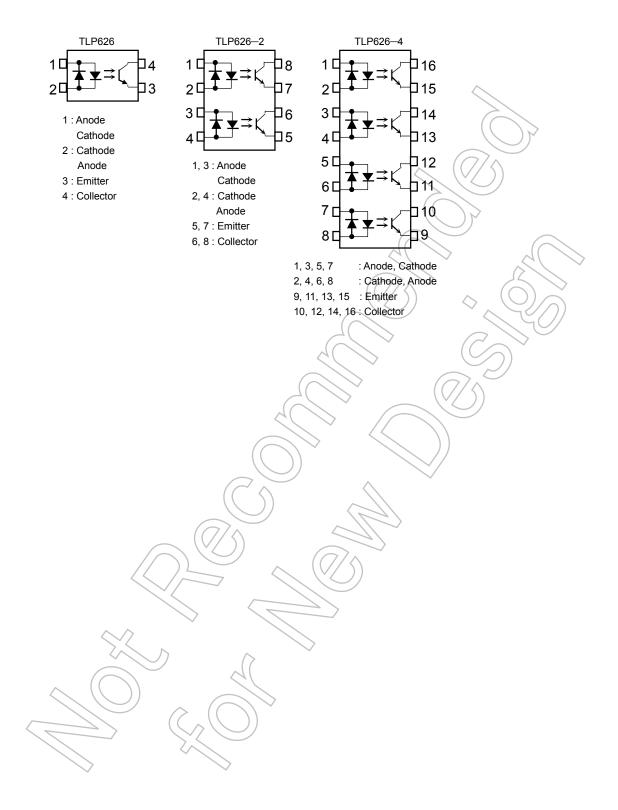


Weight: 0.54 g (typ.)





Pin Configuration (top view)



Absolute Maximum Ratings (Ta = 25°C)

				Rati	ng		
	Characteristic	S	ymbol	TLP626	TLP626-2 TLP626-4	Unit	
	Forward current		lF	60	50	mA	
	Forward current derating	Δ	l _F / °C	-0.7 (Ta ≥ 39°C)	-0.5 (Ta ≥ 25°C)	mA / °C	
Q	Pulse forward current		IFP	1 (100µs pul	se,100pps)	А	
Ц	Diode Power dissipation		PD	100	07(mW	
	Diode Power dissipation derating	ΔF	P _D /°C	-1.2 (Ta ≥ 39°C)	- 0.7 (Ta ≥ 25°C)	mW / °C	
	Junction temperature		Tj		5)	°C	
	Collector-emitter voltage	١	VCEO	55	5	V	
	Emitter-collector voltage	١	V _{ECO}	7 4()		V	
ctor	Collector current		lc	50		mA	
Detector	Collector power dissipation (1 circuit)		Pc	150	100	mW	
]	Collector power dissipation derating $(Ta \ge 25^{\circ}C, 1 \text{ circuit})$	ΔF	Pc	-1.5	-1.0	mW / °C	
	Junction temperature	G	À,	12	5 40	°C	
Sto	rage temperature range		T _{stg}	-55 to 125		°C	
Оре	erating temperature range		Popr	-55 to	100	°C	
Lea	d soldering temperature		T _{sol}	260 (1	l0 s)	°C	
Tota	al package power dissipation (1 circuit)		Рт	250	150	mW	
Tota	al package power dissipation derating (Ta \ge 25	°C, 1 circuit) ΔF	PT /°C	-2.5	-1.5	mW / °C	
Isol	ation voltage	(Note 1)	BVS	5000 (AC, 60 s	s, R.H.≤60 %)	Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Recommended Operating Conditions

Characteristic	Symbol	Min	Тур.	Max	Unit
Supply voltage	Vcc	_	5	24	V
Forward current	IF(RMS)	_	1.6	20	mA
Collector current	lc	_	1	10	mA
Operating temperature	Topr	-25	_	75	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Note 1: Device considered a two terminal: LED side pins shorted together, and detector side pins shorted together.

Electrical Characteristics (Ta = 25°C)

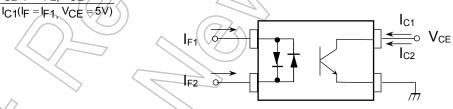
	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	I _F = ±10 mA	1.0	1.15	1.3	V
LED	Reverse current	lF	V _F = ±0.7 V	_	2.5	20	μA
	Capacitance	CT	V = 0 V, f = 1 MHz	-<	60	-	pF
	Collector-emitter breakdown voltage	V(BR)CEO	IC = 0.5 mA	55		1	V
Ŀ	Emitter-collector breakdown voltage	V(BR)ECO	IE = 0.1 mA	7)~	V
Detector		1050	V _{CE} = 24 V	$\overline{(7)}$	10	100	nA
D	Collector dark current	ICEO	V _{CE} = 24 V, Ta = 85° C	Y),))2	50	μA
	Capacitance collector to emitter	CCE	V = 0 V, f = 1 MHz		12	_	pF

Coupled Electrical Characteristics (Ta = 25°C)

	•		\searrow		1	\geq
Characteristic	Symbol	Test Condition	Min	Тур	Max	Unit
Current transfer ratio	IC / IF	$I_F = \pm 1 \text{ mA}, V_{CE} = 0.5 \text{ V}$ rank BV(Note 2)	100 200	Nr6	1200 1200	%
Low input CTR	IC / IF(low)	$I_F = \pm 0.5 \text{ mA}, V_{CE} = 1.5 \text{ V}$ rank BV(Note 2)	50 100	$\widehat{\mathcal{D}}$		%
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = 0.5 \text{ mA}, I_F = \pm 1 \text{ mA}$ $I_C = 1 \text{ mA}, I_F = \pm 1 \text{ mA}$ rank BV(Note 2)	Ø	— 0.2	0.4	V
Off-state collector current	Ic(off)	$V_F = \pm 0.7 V, V_{CE} = 24 V$))=	1	0.4 10	μA
CTR symmetry (Note 1)	I _C (ratio)	1 _C (I _F = -1 mA) / I _C (I _F = 1 mA)	0.5	_	2	_

Note 1

IC(ratio) = $\frac{I_{C2}(I_F = I_{F2}, V_{CE} = 5V)}{I_{C2}(I_F = I_{F2}, V_{CE} = 5V)}$



Note 2: Only TLP626 is applied to BV rank items.

Coupled Electrical Characteristics (Ta = -25 to 75°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Current transfer ratio		I _F = 1 mA, V _{CE} = 0.5 V	50	_	_	%
	IC / IF	rank BV(Note 1)	100	_	_	
Low input CTR		IF = 0.5 mA, VCE = 1.5 V		50		%
	IC / IF(low)	rank BV(Note 1)		100		70

Note 1: Only TLP626 is applied to BV rank items.

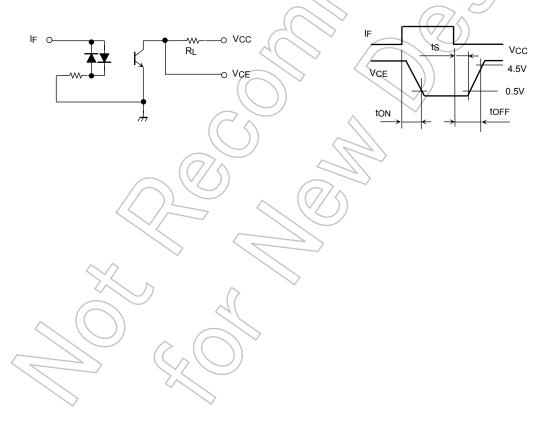
Isolation Characteristics (Ta = 25°C)

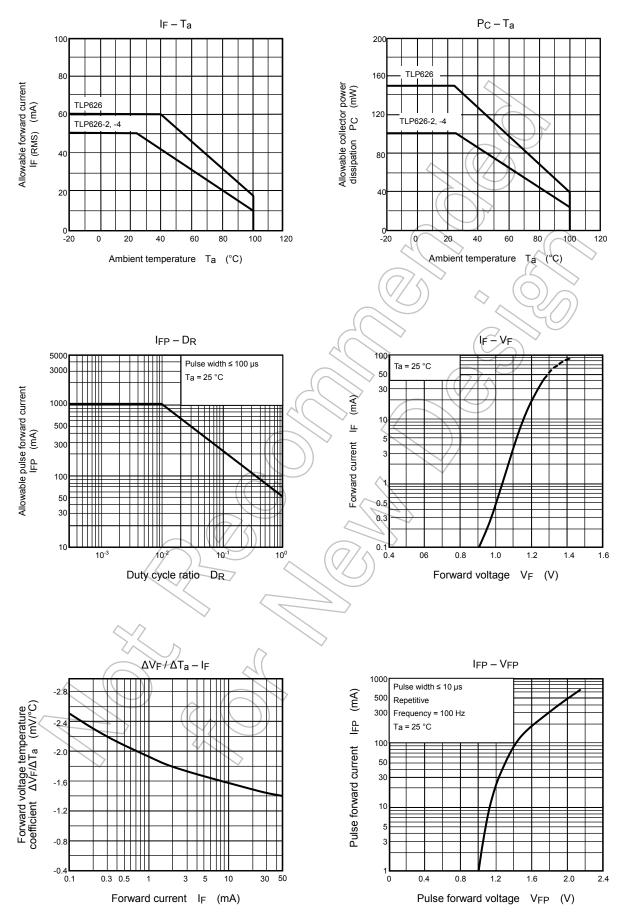
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	CS	V _S = 0 V, f = 1 MHz	-	0.8	_	pF
Isolation resistance	Rs	V _S = 500 V, R.H.≤60 %	5×10 ¹⁰	10 ¹⁴	_	Ω
Isolation voltage	BVs	AC, 60 s	5000	/	_	Vrms

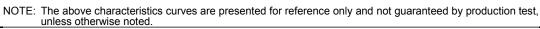
Switching Characteristics (Ta = 25°C)

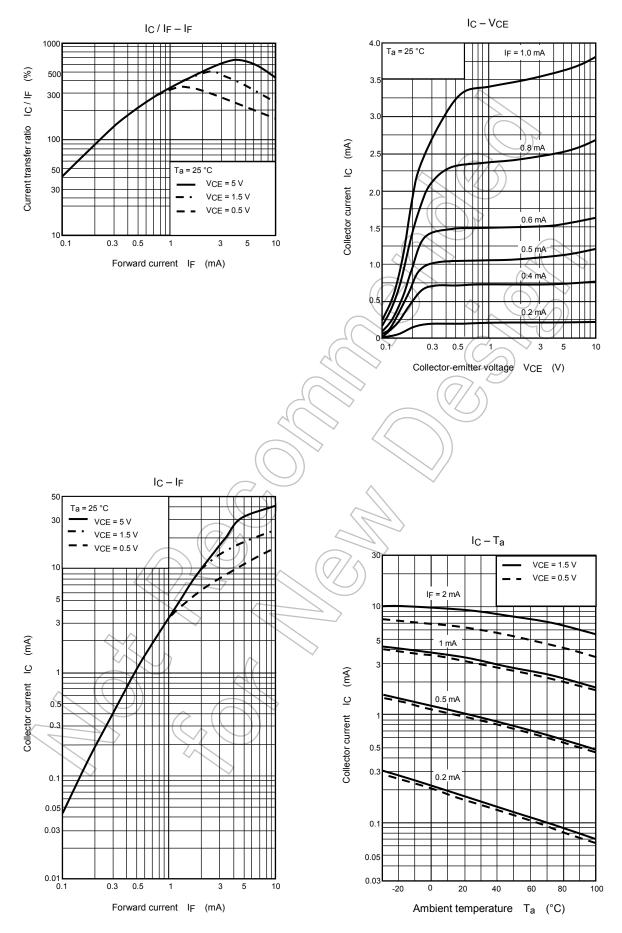
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Rise time	tr	$V_{CC} = 10 \text{ V}, \text{ I}_{C} = 2 \text{ mA}$ $R_{L} = 100 \Omega$		8	Ι	
Fall time	t _f		J.	8	_	
Turn-on time	t _{on}		-	10	ha ha	μs
Turn-off time	toff		>	8	L.	\searrow
Turn-on time	ton	(7/5)	-	10		
Storage time	ts	R _L = 4.7 kΩ (Fig.1) V _{CC} = 5 V, I_F = ±1.6 mA		50	$\mathcal{I}_{\mathcal{A}})$	μs
Turn-off time	toff		-	300	19	

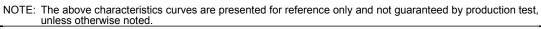
Fig. 1: Switching operating conditions



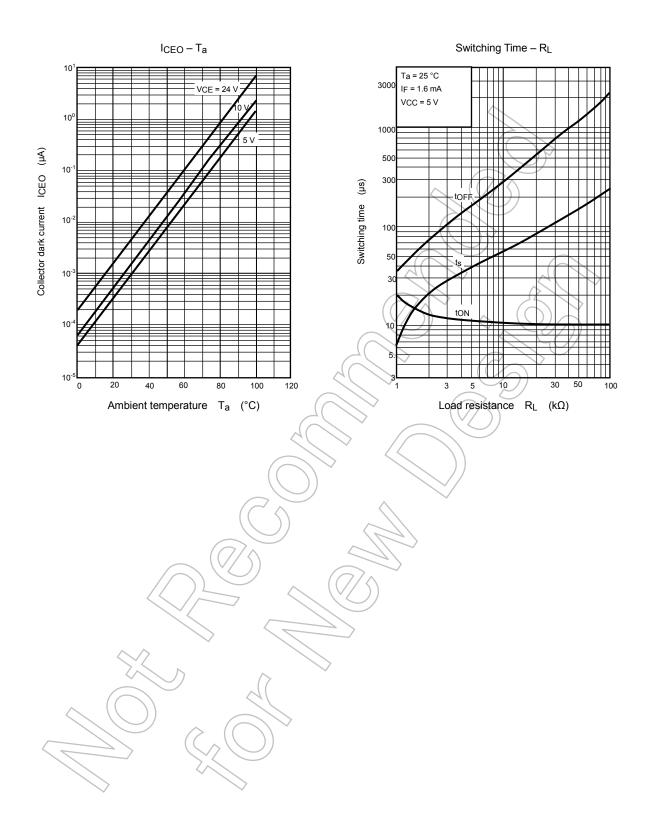








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NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

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